October 2000



74LCXH245 Low Voltage Bidirectional Transceiver with Bushold

General Description

The LCXH245 contains eight non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is designed for low voltage (2.5V and 3.3V) V_{CC} applications. The T/\overline{R} input determines the direction of data flow through the device. The OE input disables both the A and B ports by placing them in a high impedance state.

The LCXH245 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation. The LCXH16244 data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level.

Features

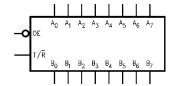
- 5V tolerant control inputs
- 2.3V-3.6V V_{CC} specifications provided
- \blacksquare 7.0 ns t_{PD} max (V $_{CC}$ = 3.3V), 10 μA I_{CC} max
- Power down high impedance outputs
- \pm 24 mA output drive (V_{CC} = 3.0V)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- Bushold on inputs eliminates the need for external pull-up/pull-down resistors
- ESD performance: Human body model > 2000V Machine model > 200V

Ordering Code:

Order Number	Package Number	Package Description
74LCXH245WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LCXH245SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCXH245MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LCXH245MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



Pin Descriptions

Pin Names	Description
ŌĒ	Output Enable Input
T/R	Transmit/Receive Input
A ₀ -A ₇	Side A Inputs or 3-STATE Outputs (Bushold)
B ₀ -B ₇	Side B Inputs or 3-STATE Outputs (Bushold)

Connection Diagram



GTO™ is a trademark of Fairchild Semiconductor Corporation.

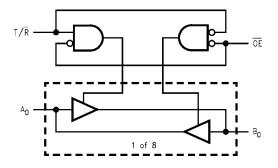
Truth Table

Inp	outs	2.1.1.	
OE	T/R	Outputs	
L	L	Bus B ₀ – B ₇ Data to Bus A ₀ – A ₇	
L	Н	Bus A ₀ – A ₇ Data to Bus B ₀ – B ₇	
Н	Х	HIGH Z State on A ₀ – A ₇ , B ₀ – B ₇ (Note 1)	

- H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial Z = High Impedance

Note 1: Unused bus terminals during HIGH Z State must be held HIGH or LOW.

Logic Diagram



mΑ

mΑ

°C

Absolute Maximum Ratings(Note 2) Symbol Parameter Value Conditions Units -0.5 to +7.0 ٧ Supply Voltage V_{CC} T/R, OE ٧ V_{I} 0.5 to +7.0 I/O Ports -0.5 to $V_{CC} + 0.5$ ٧o DC Output Voltage -0.5 to +7.0 Output in 3-STATE ٧ Output in HIGH or LOW State (Note 3) -0.5 to $V_{CC} + 0.5$ DC Input Diode Current -50 $V_1 < GND$ mΑ I_{IK} DC Output Diode Current -50 V_O < GND I_{OK} mΑ +50 $V_O > V_{CC}$ DC Output Source/Sink Current ±50 mΑ I_{O}

±100

±100

-65 to +150

Recommended Operating Conditions (Note 4)

DC Supply Current per Supply Pin

DC Ground Current per Ground Pin

Storage Temperature

 I_{CC}

I_{GND} T_{STG}

Symbol	Parameter			Max	Units
V _{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	V
V _I	Input Voltage		0	V _{CC}	V
Vo	Output Voltage	HIGH or LOW State	0	V _{CC}	V
		3-STATE	0	5.5	V
I _{OH} /I _{OL}	Output Current	$V_{CC} = 3.0V - 3.6V$		±24	
		$V_{CC} = 2.7V - 3.0V$ $V_{CC} = 2.3V - 2.7V$		±12	mA
		$V_{CC} = 2.3V - 2.7V$		±8	
T _A	Free-Air Operating Temperature		-40	85	°C
Δt/ΔV	Input Edge Rate, $V_{IN} = 0.8V - 2.0V$, $V_{CC} = 3.0V$		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 3: I_O Absolute Maximum Rating must be observed.

Note 4: Floating or unused control inputs must be HIGH or LOW.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V _{CC}	T _A = -40°C	to +85°C	Units	
Syllibol	Farameter	Conditions	(V)	Min	Max	Units	
V _{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V	
			2.7 – 3.6	2.0		7 v	
V _{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V	
			2.7 - 3.6		0.8	7 '	
V _{OH}	HIGH Level Output Voltage	$I_{OH} = -100 \mu A$	2.3 - 3.6	V _{CC} - 0.2			
		$I_{OH} = -8 \text{ mA}$	2.3	1.8		Ī	
		$I_{OH} = -12 \text{ mA}$	2.7	2.2		V	
		$I_{OH} = -18 \text{ mA}$	3.0	2.4		Ī	
		I _{OH} = -24 mA	3.0	2.2		Ī	
V _{OL}	LOW Level Output Voltage	$I_{OL} = 100 \mu A$	2.3 – 3.6		0.2		
		I _{OL} = 8mA	2.3		0.6	Ī	
		I _{OL} = 12 mA	2.7		0.4	V	
		I _{OL} = 16 mA	3.0		0.4	Ī	
		I _{OL} = 24 mA	3.0		0.55		
I ₁	Input Leakage Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		±5.0	μΑ	

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V _{CC}	$T_A = -40^{\circ}C$ to $+85^{\circ}C$		Units	
Зушьог	Farameter	Conditions	(V)	Min	Max	Ullits	
I _{I(HOLD)}	Bushold Input Minimum	$V_{IN} = 0.7V$	2.3	45			
	Drive Hold Current	$V_{IN} = 1.7V$	2.3	-45		μА	
		$V_{IN} = 0.8V$	3.0	75		μΛ	
		V _{IN} = 2.0V	3.0	-75			
I _{I(OD)}	Bushold Input Over-Drive	(Note 6)	2.7	300			
	Current to Change State	nange State (Note 7)		-300		μА	
		(Note 6)	3.6	450		μΑ	
		(Note 7)	3.6	-450			
l _{OZ}	3-STATE I/O Leakage	$V_O = V_{CC}$ or GND	2.3 – 3.6		±5.0	μΑ	
I _{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		10		
		$3.6V \le V_I, V_O \le 5.5V \text{ (Note 5)}$	2.3 – 3.6		±10	μΑ	
Δl _{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 - 3.6		500	μА	

Note 5: Outputs disabled or 3-STATE only.

Note 6: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 7: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

AC Electrical Characteristics

		$T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $R_L = 500\Omega$						
Compleal	Parameter	V _{CC} = 3.3	3V ± 0.3V	$V_{CC} = 2.7V$		$\rm V_{CC}=2.5V\pm0.2V$		Units
Symbol	Parameter	C _L = 50 pF		C _L = 50 pF		C _L = 30 pF		Units
		Min	Max	Min	Max	Min	Max	1
t _{PHL}	Propagation Delay	1.5	7.0	1.5	8.0	1.5	8.4	
t _{PLH}	A_n to B_n or B_n to A_n	1.5	7.0	1.5	8.0	1.5	8.4	ns
t _{PZL}	Output Enable Time	1.5	8.5	1.5	9.5	1.5	10.5	ns
t _{PZH}		1.5	8.5	1.5	9.5	1.5	10.5	115
t _{PLZ}	Output Disable Time	1.5	7.5	1.5	8.5	1.5	9.0	ns
t_{PHZ}		1.5	7.5	1.5	8.5	1.5	9.0	115
toshl	Output to Output Skew		1.0					ns
toslh	(Note 8)		1.0					118

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	v _{cc}	$T_A = 25^{\circ}C$	Units
Oyillboi			(V)	Typical	Oilles
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_L = 50 \text{ pF}, V_{IH} = 3.3V, V_{IL} = 0V$	3.3	0.8	V
		$C_L = 30 \text{ pF, } V_{IH} = 2.5 \text{V, } V_{IL} = 0 \text{V}$	2.5	0.6	V
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	-0.8	V
		$C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{V}, V_{IL} = 0 \text{V}$	2.5	-0.6	· ·

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance	V _{CC} = Open, V _I = 0V or V _{CC}	7	pF
C _{I/O}	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} , $f = 10$ MHz	25	pF

AC LOADING and WAVEFORMS Generic for LCX Family

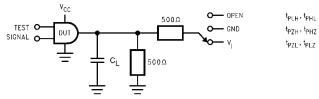
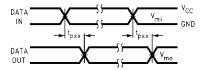
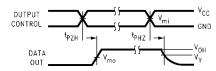


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

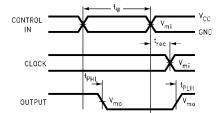
Test	Switch
t _{PLH} , t _{PHL}	Open
t _{PZL} , t _{PLZ}	6V at $V_{CC} = 3.3 \pm 0.3V$; and 2.7V V_{CC} x 2 at $V_{CC} = 2.5 \pm 0.2V$
t _{PZH} , t _{PHZ}	GND



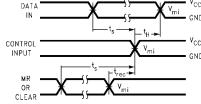
Waveform for Inverting and Non-Inverting Functions



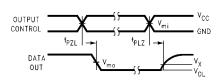
3-STATE Output High Enable and Disable Times for Logic



Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

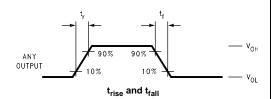
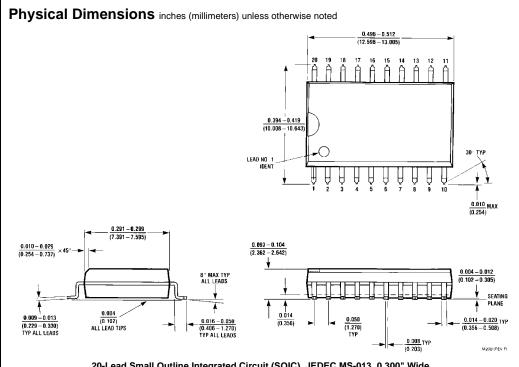
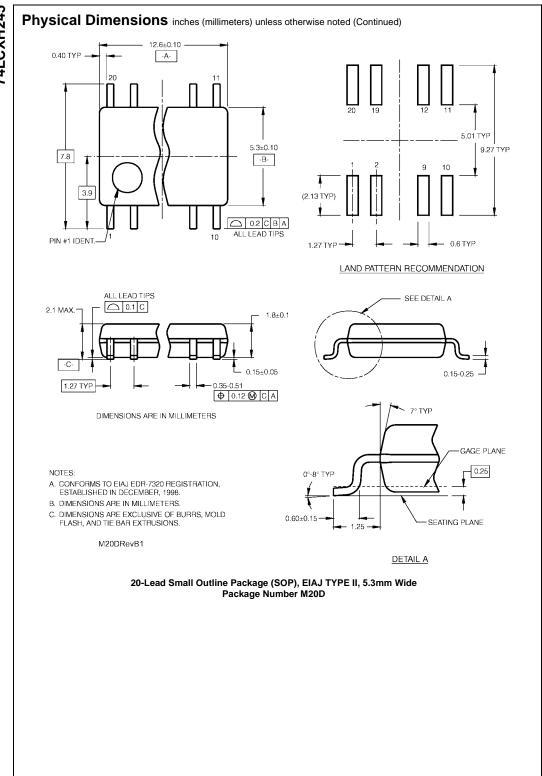


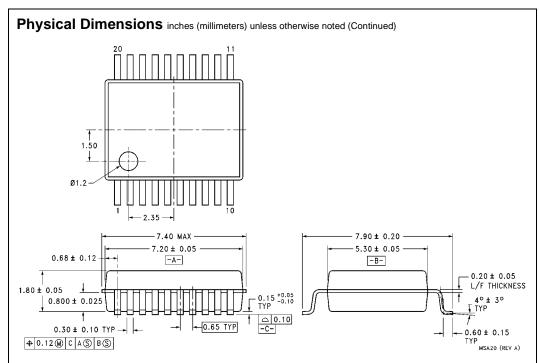
FIGURE 2. Waveforms (Input Characteristics; f =1MHz, $t_r = t_f = 3ns$)

Symbol	V _{CC}				
Cymbol	$\textbf{3.3V} \pm \textbf{0.3V}$	2.7V	2.5V ± 0.2V		
V_{mi}	1.5V	1.5V	V _{CC} /2		
V_{mo}	1.5V	1.5V	V _{CC} /2		
V _x	V _{OL} + 0.3V	V _{OL} + 0.3V	V _{OL} + 0.15V		
V _v	V _{OH} – 0.3V	V _{OH} – 0.3V	V _{OH} – 0.15V		

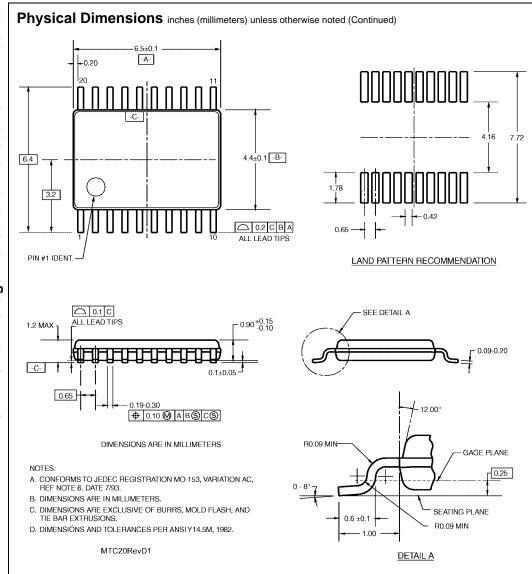


20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide Package Number M20B





20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide Package Number MSA20



20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC20

Fairchild does not assume any responsibility for use of any circuitry described, no circuit patent licenses are implied and Fairchild reserves the right at any time without notice to change said circuitry and specifications.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

www.fairchildsemi.com

This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.